# 2SB1499, 2SB1499A

### Silicon PNP epitaxial planar type

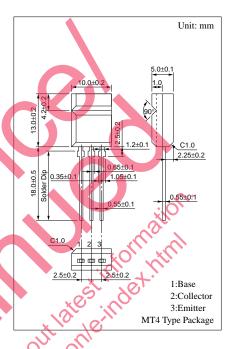
For low-freauency power amplification

#### Features

- $\bullet~$  High forward current transfer ratio  $h_{FE}$  which has satisfactory linearity
- ullet Low collector to emitter saturation voltage  $V_{\text{CE(sat)}}$
- · Allowing automatic insertion with radial taping

#### Absolute Maximum Ratings $(T_C=25^{\circ}C)$

Parameter		Symbol	Ratings	Unit	
Collector to	2SB1499	V	-60	v	
base voltage	2SB1499A	$V_{CBO}$	-80		
Collector to	2SB1499	N/	-60	V	
emitter voltage	2SB1499A	V <sub>CEO</sub>	-80		
Emitter to base voltage		V <sub>EBO</sub>	-5	V	
Peak collector current		$I_{CP}$	-8	A	
Collector current		$I_{C}$	-4	A	
Collector power	T <sub>C</sub> =25°C	D	15	W	
dissipation	Ta=25°C	P <sub>d</sub>	2	W	
Junction temperature		$T_{j}$	150	°C	
Storage temperature		$T_{\rm stg}$	-55 to +150	°C	



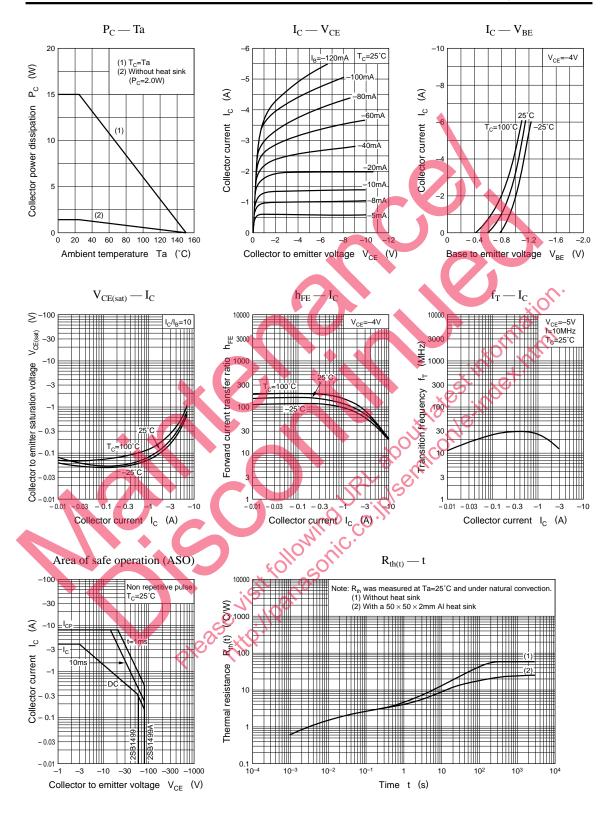
### Electrical Characteristics (T<sub>C</sub>=25°C)

Parameter		Symbol		Conditions	min	typ	max	Unit
Collector cutoff	2SB1499	ı	$V_{CE} = -60V, V_{BE} = 0$				-400	μА
current	2SB1499A	I <sub>CES</sub>	$V_{CE} = -80V, V_{BE} = 0$				-400	
Collector cutoff	2SB1499		$V_{CE} = -30 \text{W} I_B = 0$ $V_{QE} = 60 \text{V}, I_B = 0$				-700	μА
current	2SB1499A	CEO					-700	
Emitter cutoff curren	ıt	$I_{\mathrm{EBO}}$	$V_{\rm EB} = -5$	$V_{C}=0$			-1	mA
Collector to emitter	2SB1499		$I_{\rm C} = 30 { m mA}, I_{\rm B} = 0$	-60			V	
voltage	2SB1499A	V <sub>CEO</sub>		-80				
Forward current transfer ratio		h <sub>EE</sub>	$V_{\rm CE} = -4$	$V, I_C = -1A$	70		250	
		h <sub>FE2</sub>	$V_{CE} = -4V$	$V, I_C = -3A$	15			
Base to emitter volta	ge	$V_{BE}$	$V_{CE} = -4$	$V, I_C = -3A$			-2	V
Collector to emitter sat	uration voltage	V <sub>CE(sat)</sub>	$I_C = -4A$ ,	$I_B = -0.4A$			-1.5	V
Transition frequency		$f_T$	$V_{CE} = -10$	$V, I_C = -0.1A, f = 10MHz$		30		MHz
Turn-on time		t <sub>on</sub>	$I_C = -4A$ , $I_{B1} = -0.4A$ , $I_{B2} = 0.4A$			0.2		μs
Storage time		t <sub>stg</sub>				0.5		μs
Fall time		t <sub>f</sub>				0.2		μs

#### \*h<sub>FE1</sub> Rank classification

Rank	Q	P
h <sub>FE1</sub>	70 to 150	120 to 250

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